TABLE I. DEVICE PARAMETERS 1/

JPL PART #	MFG	MFG PART #	PACKAGE	DETAIL	ELECTRICAL	RADIATION
ST12212-			STYLE	SCREENING	CHARACTERISTICS &	(TID) LEVEL
				TESTS	GROUP A TESTS	RAD(Si)
DN415ØBR	MSC	1N415Ø	DO-35	MIL-S-	MIL-S-195ØØ/231	1ØØk 3/
			2/	195ØØ/231	(TABLE I)	

NOTES:

- 1/ This drawing in conjunction with CS515581, imposes all requirements for procurement of these devices.
- 2/ Device physical dimensions shall conform to MIL-S-195ØØ/231, Figure 1.
- 3/ Sufficient radiation tolerance to this TID level is guaranteed by design for this device. (See CS515581, Paragraph 4.7.7).
- 4. Final finish of leads shall be hot solder dip in accordance with MIL-S-195ØØ.
- 5. This standard takes precedence over documents referenced herein.

RELEASED THRU SE	CTION 356 DATA MANAGEMENT:	DATE:	
REVISION: B	APPROVED BY:	DATE:	
	APPROVED SOURCE(S)		THE ITEM LISTED IN THE APPROVED SOURCE BLOCK AND IDENTIFIED BY VENDOR NAME, ADDRESS, AND PART NUMBER WILL BE EVALUATED AND TESTED BY THE JPL ELECTRONIC PARTS RELIABILITY SECTION OR ITS DELEGATED ALTERNATE BEFORE BEING APPROVED FOR USE. NON-JPL USERS SHALL CHECK WITH THE ELECTRONIC PARTS RELIABILITY SECTION ON THE STATUS OF THE PART'S APPROVAL BEFORE USING.
VENDOR PART NO	VENDOR	JPL PART NO	
JET PROP	Pulsion Laboratory California instituti	E OF TECHNOL	OGY CAGE NO 23835
Procurement specification: CS515581 Screening specification: ZPP-2Ø73-GEN	TITLE: DIODE, SILICON, LOW POWER SWITCHING, 2ØØmA, 5ØV		DETAIL SPECIFICATION
			ST 12212
Custodian: Electronic Parts			SHEET 1 OF 1